Application No.: 10/575,680

AMENDMENTS TO THE CLAIMS

Please enter the following amendments:

1. (Currently Amended) A two-beam semiconductor laser device comprising:

a two-beam semiconductor element having first and second semiconductor laser elements

that can be driven independently and that are formed integrally on a substrate; and

a submount having, mounted on a front part thereof, the two-beam semiconductor laser

element with a light-emitting face thereof directed forward and having first and second electrode

pads connected to electrodes of the first and second semiconductor laser elements by being kept

in contact therewith,

wherein no photodetector is provided on the submount,

wherein the first and second electrode pads are formed to extend farther behind the two-

beam semiconductor laser element, and are wire-bonded behind the two-beam semiconductor

laser element at positions directly behind the two-beam semiconductor laser element with respect

to a laser-light-emitting direction of the two-beam semiconductor element, and

wherein a lateral width of the submount along the front part of the submount is 400 μm or

more but 700 μm or less.

2. (Original) The two-beam semiconductor laser device of claim 1,

wherein the first and second electrode pads are wire-bonded at a rear end of the

submount

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(Previously Presented) The two-beam semiconductor laser device of claim 1,
wherein a distance from the rear end of the two-beam semiconductor laser element to a

position where the first and second electrode pads are wire-bonded is 300 μm or shorter.

4. (Canceled)

5. (Currently Amended) The two-beam semiconductor laser device of claim 1, further

comprising:

a metal frame;

wherein the submount is mounted directly on the frame, and

no photodetector is directly mounted on the frame.

6. (Previously Presented) The two-beam semiconductor laser device of claim 5,

wherein the two-beam semiconductor laser device is built as a three-terminal two-beam

semiconductor laser device having only three terminals.

7. (Currently Amended) The two-beam semiconductor laser device of claim 5, further

comprising:

three bonding wires, each bonded to a location behind the submount and to one of an

electrode of the two-beam semiconductor element, the first electrode pad, and the second

electrode pad.

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